FM32L278/L276/L274/L272

3V Integrated Processor Companion with Memory



Features

High Integration Device Replaces Multiple Parts

- Serial Nonvolatile Memory
- Low Voltage Reset
- Watchdog Timer
- Early Power-Fail Warning/NMI
- Two 16-bit Event Counters
- Serial Number with Write-lock for Security

Processor Companion

- Active-low Reset Output for V_{DD} and Watchdog
- Programmable V_{DD} Reset Trip Point
- Manual Reset Filtered and Debounced
- Programmable Watchdog Timer
- Dual Battery-backed Event Counter Tracks System Intrusions or other Events
- Comparator for Early Power-Fail Interrupt
- 64-bit Programmable Serial Number with Lock

Ferroelectric Nonvolatile RAM

- 4Kb, 16Kb, 64Kb, and 256Kb versions
- Unlimited Read/Write Endurance
- 45 year Data Retention
- NoDelayTM Writes

Fast Two-wire Serial Interface

- Up to 1 MHz Maximum Bus Frequency
- Supports Legacy Timing for 100 kHz & 400 kHz
- Device Select Pins for up to 4 Memory Devices
- Companion Controlled via 2-wire Interface

Easy to Use Configurations

- Operates from 2.7 to 3.6V
- 14-pin "Green"/RoHS SOIC package (-G)
- Pin Compatible with FM31L27x Series
- Low Operating Current
- -40°C to +85°C Operation
- Underwriters Laboratory (UL) Recognized

Description

The FM32L27x is a family of integrated devices that includes the most commonly needed functions for processor-based systems. Major features include nonvolatile memory available in various sizes, low-VDD reset, watchdog timer, nonvolatile event counter, lockable 64-bit serial number area, and general purpose comparator that can be used for an early power-fail (NMI) interrupt or other purpose. The family operates from 2.7 to 3.6V.

The FM32L27x family is software and pinout compatible with the FM31L27x family which also includes a real-time clock. The common features allow a system design that easily can be assembled with or without timekeeping by simply selecting the FM31L27x or FM32L27x, respectively.

Each FM32L27x provides nonvolatile RAM available in sizes including 4Kb, 16Kb, 64Kb, and 256Kb versions. Fast write speed and unlimited endurance allow the memory to serve as extra RAM or conventional nonvolatile storage. This memory is truly nonvolatile rather than battery backed.

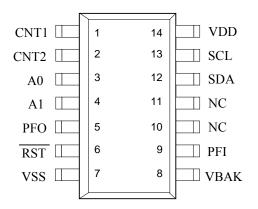
The processor companion includes commonly needed CPU support functions. Supervisory functions include a reset output signal controlled by either a low VDD condition or a watchdog timeout. /RST goes active when VDD drops below a programmable threshold and remains active for 100 ms after VDD rises above the trip point. A programmable watchdog timer runs from 100 ms to 3 seconds. The watchdog timer is optional, but if enabled it will assert the reset signal for 100 ms if not restarted by the host before the timeout. A flag-bit indicates the source of the reset.

A general-purpose comparator compares an external input pin to the onboard 1.2V reference. This is useful for generating a power-fail interrupt (NMI) but can be used for any purpose. The family also includes a programmable 64-bit serial number that can be locked making it unalterable.

Additionally the FM32L27x offers a dual event counter that tracks the number of rising or falling edges detected on dedicated input pins. The counter can optionally be battery backed and even battery operated by attaching a backup power source to the VBAK pin. If VBAK is connected to a battery or capacitor, then events will be counted even in the absence of $V_{\rm DD}$.

This product conforms to specifications per the terms of the Ramtron standard warranty. The product has completed Ramtron's internal qualification testing and has reached production status.

Pin Configuration



Pin Name	Function
CNT1, CNT2	Event Counter Inputs
A0, A1	Device Select inputs
PFO	Early Power-Fail Output
/RST	Reset Input/Output
PFI	Early Power-fail Input
SDA	Serial Data
SCL	Serial Clock
VBAK	Battery-Backup Supply
VDD	Supply Voltage
VSS	Ground

Ordering Information											
Base Configuration	Memory Size	Operating Voltage	Reset Threshold	Ordering Part Number							
FM32L278	256Kb	2.7-3.6V	2.6V, 2.9V	FM32L278-G							
	256Kb	2.7-3.6V	2.6V, 2.9V	FM32L278-GTR (tape&reel)							
FM32L276	64Kb	2.7-3.6V	2.6V, 2.9V	FM32L276-G							
	64Kb	2.7-3.6V	2.6V, 2.9V	FM32L276-GTR (tape&reel)							
FM32L274	16Kb	2.7-3.6V	2.6V, 2.9V	FM32L274-G							
	16Kb	2.7-3.6V	2.6V, 2.9V	FM32L274-GTR (tape&reel)							
FM32L272	4Kb	2.7-3.6V	2.6V, 2.9V	FM32L272-G							
	4Kb	2.7-3.6V	2.6V, 2.9V	FM32L272-GTR (tape&reel)							

Other memory configurations may be available. Please contact the factory for more information.

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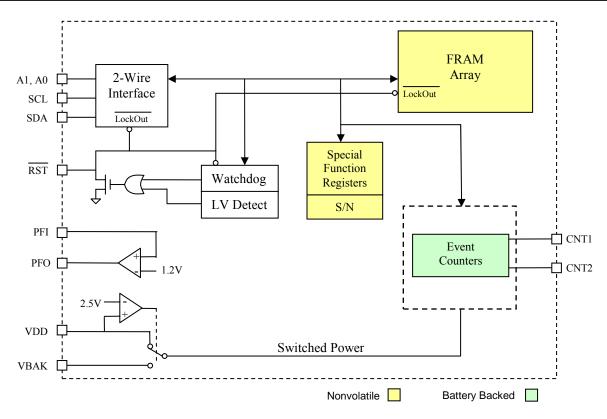


Figure 1. Block Diagram

Pin Descriptions

Pin Name	Type	Pin Description
A0, A1	Input	Device select inputs are used to address multiple memories on a serial bus. To select the
		device the address value on the two pins must match the corresponding bits contained in the device address. The device select pins are pulled down internally.
CNT1,	Input	Event Counter Inputs: These battery-backed inputs increment counters when an edge is
CNT2	1	detected on the corresponding CNT pin. The polarity is programmable. These pins should not be left floating. Tie to ground if pins are not used.
PFO	Output	Power Fail Output: This is the early power-fail output.
/RST	I/O	Active low reset output with weak pull-up. Also input for manual reset.
SDA	I/O	Serial Data & Address: This is a bi-directional line for the two-wire interface. It is open-
		drain and is intended to be wire-OR'd with other devices on the two-wire bus. The input
		buffer incorporates a Schmitt trigger for noise immunity and the output driver includes
		slope control for falling edges. A pull-up resistor is required.
SCL	Input	Serial Clock: The serial clock line for the two-wire interface. Data is clocked out of the
		part on the falling edge, and in on the rising edge. The SCL input also incorporates a
		Schmitt trigger input for noise immunity.
PFI	Input	Early Power-fail Input: Typically connected to an unregulated power supply to detect an
		early power failure. This pin should not be left floating.
VBAK	Supply	Backup supply voltage: A 3V battery or a large value capacitor. If no backup supply is
		used, this pin should be tied to ground and the VBC bit should be cleared. The trickle
		charger is UL recognized and ensures no excessive current when using a lithium battery.
VDD	Supply	Supply Voltage
VSS	Supply	Ground

Overview

The FM32L27x family combines a serial nonvolatile RAM with a processor companion. The companion is a highly integrated peripheral including a processor supervisor, a comparator used for early power-fail warning, nonvolatile event counters, and a 64-bit serial number. The FM32L27x integrates these complementary but distinct functions that share a common interface in a single package. Although monolithic, the product is organized as two logical devices, the F-RAM memory and the companion. From the system perspective they appear to be two separate devices with unique IDs on the serial bus.

The FM32L27x provides the same functions as the FM31L27x with the exception of the real-time clock. This makes it easy to develop a common design that can either include timekeeping by using the FM31L27x or exclude it by using the FM32L27x. All other features are identical. The register address map is even preserved so that software can be identical.

The memory is organized as a stand-alone 2-wire nonvolatile memory with a standard device ID value. The companion functions are accessed under their own 2-wire device ID. This allows the companion functions to be read while maintaining the most recently used memory address. The companion functions are controlled by 16 special function registers. The event counter circuits and related registers are maintained by the power source on the VBAK pin, allowing them to operate from battery or backup capacitor power when $V_{\rm DD}$ drops below a set threshold. Each functional block is described below.

Memory Operation

The FM32L27x is a family of products available in different memory sizes including 4Kb, 16Kb, 64Kb, and 256Kb. The family is software compatible, all versions use consistent two-byte addressing for the memory device. This makes the lowest density device different from its stand-alone memory counterparts but makes them compatible within the entire family.

Memory is organized in bytes, for example the 4Kb memory is 512 x 8 and the 256Kb memory is 32,768 x 8. The memory is based on F-RAM technology. Therefore it can be treated as RAM and is read or written at the speed of the two-wire bus with no delays for write operations. It also offers effectively unlimited write endurance unlike other nonvolatile memory technologies. The 2-wire interface protocol is described further on page 13.

The memory array can be write-protected by software. Two bits in the processor companion area

(WP0, WP1 in register 0Bh) control the protection setting as shown in the following table. Based on the setting, the protected addresses cannot be written and the 2-wire interface will not acknowledge any data to protected addresses. The special function registers containing these bits are described in detail below.

Write protect addresses	WP1	WP0
None	0	0
Bottom 1/4	0	1
Bottom 1/2	1	0
Full array	1	1

Processor Companion

In addition to nonvolatile RAM, the FM32L27x family incorporates a highly integrated processor companion. It includes a low voltage reset, a programmable watchdog timer, battery-backed event counters, a comparator for early power-fail detection or other purposes, and a 64-bit serial number.

Processor Supervisor

Supervisors provide a host processor two basic functions: detection of power supply fault conditions and a watchdog timer to escape a software lockup condition. All FM32L27x devices have a reset pin (/RST) to drive the processor reset input during power faults (and power-up) and software lockups. It is an open drain output with a weak internal pull-up to V_{DD}. This allows other reset sources to be wire-OR'd to the /RST pin. When V_{DD} is above the programmed trip point, /RST output is pulled weakly to V_{DD}. If V_{DD} drops below the reset trip point voltage level (V_{TP}) the /RST pin will be driven low. It will remain low until V_{DD} falls too low for circuit operation which is the V_{RST} level. When V_{DD} rises again above V_{TP}, /RST will continue to drive low for at least 100 ms (t_{RPU}) to ensure a robust system reset at a reliable V_{DD} level. After t_{RPU} has been met, the /RST pin will return to the weak high state. While /RST is asserted, serial bus activity is locked out even if a transaction occurred as V_{DD} dropped below V_{TP} . A memory operation started while V_{DD} is above V_{TP} will be completed internally.

Figure 2 below illustrates the reset operation in response to the V_{DD} voltage.

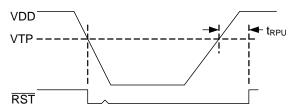


Figure 2. Low Voltage Reset

The bit VTP controls the trip point of the low voltage detect circuit. It is located in register 0Bh, bit 0. Note that the bit 1 location is a "don't care".

V_{TP}	VTP
$2.\overline{6}V$	0
2.9V	1

The watchdog timer can also be used to assert the reset signal (/RST). The watchdog is a free running programmable timer. The period can be software programmed from 100 ms to 3 seconds in 100 ms increments via a 5-bit nonvolatile register. All programmed settings are minimum values and vary with temperature according to the operating specifications. The watchdog has two additional controls associated with its operation, a watchdog enable bit (WDE) and timer restart bits (WR). Both the enable bit must be set and the watchdog must timeout in order to drive /RST active. If a reset event occurs, the timer will automatically restart on the rising edge of the reset pulse. If WDE=0, the watchdog timer runs but a watchdog fault will not cause /RST to be asserted low. The WTR flag will be set, indicating a watchdog fault. This setting is useful during software development and the developer does not want /RST to drive. Note that setting the maximum timeout setting (11111b) disables the counter to save power. The second control is a nibble that restarts the timer preventing a reset. The timer should be restarted after changing the timeout value.

The watchdog timeout value is located in register 0Ah, bits 4-0, and the watchdog enable is bit 7. The watchdog is restarted by writing the pattern 1010b to the lower nibble of register 09h. Writing this pattern will also cause the timer to load new timeout values. Writing other patterns to this address will not affect its operation. Note the watchdog timer is freerunning. Prior to enabling it, users should restart the timer as described above. This assures that the full timeout period will be set immediately after enabling. The watchdog is disabled when V_{DD} is below V_{TP} . The following table summarizes the watchdog bits.

Watchdog timeout WDT4-0 0Ah, bits 4-0 Watchdog enable WDE 0Ah, bit 7 Watchdog restart WR3-0 09h, bits 3-0

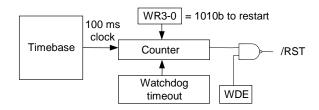


Figure 3. Watchdog Timer

Manual Reset

The /RST pin is bi-directional and allows the FM32L27x to filter and de-bounce a manual reset switch. The /RST input detects an external low condition and responds by driving the /RST signal low for 100 ms.

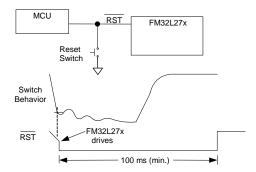


Figure 4. Manual Reset

Note that an internal weak pull-up on /RST eliminates the need for additional external components.

Reset Flags

In case of a reset condition, a flag will be set to indicate the source of the reset. A low $V_{\rm DD}$ reset or manual reset is indicated by the POR flag, register 09h bit 6. A watchdog reset is indicated by the WTR flag, register 09h bit 7. Note that the flags are internally set in response to reset sources, but they must be cleared by the user. When the register is read, it is possible that both flags are set if both have occurred since the user last cleared them.

Early Power Fail Comparator

An early power fail warning can be provided to the processor well before V_{DD} drops out of spec. The comparator is used to create a power fail interrupt (NMI). This can be accomplished by connecting the PFI pin to the unregulated power supply via a resistor divider. An application circuit is shown below.

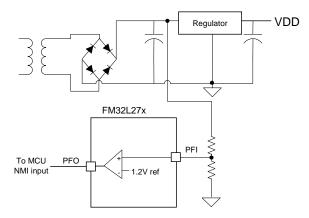


Figure 5. Comparator as Early Power-Fail Warning

The voltage on the PFI input pin is compared to an onboard 1.2V reference. When the PFI input voltage drops below this threshold, the comparator will drive the PFO pin to a low state. The comparator has 100 mV (max) of hysteresis to reduce noise sensitivity, only for a rising PFI signal. For a falling PFI edge, there is no hysteresis.

The comparator is a general purpose device and its application is not limited to the NMI function.

Note: The maximum voltage on the comparator input PFI is limited to 3.75V under normal operating conditions.

Event Counter

The FM32L27x offers the user two battery-backed event counters. Input pins CNT1 and CNT2 are programmable edge detectors. Each clocks a 16-bit counter. When an edge occurs, the counters will increment their respective registers. Counter 1 is located in registers 0Dh and 0Eh, Counter 2 is located in registers 0Fh and 10h. These register values can be read anytime VDD is above VTP, and they will be incremented as long as a valid VBAK power source is provided. To read, set the RC bit register 0Ch bit 3 to 1. This takes a snapshot of all four counter bytes allowing a stable value even if a count occurs during the read. The registers can be written by software allowing the counters to be cleared or initialized by the system. Counts are blocked during a write operation. The two counters can be cascaded to create a single 32-bit counter by setting the CC control bit (register 0Ch). When cascaded, the CNT1 input will cause the counter to increment. CNT2 is not used in this mode.

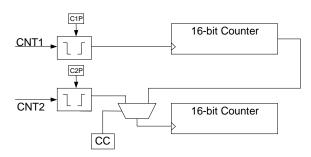


Figure 6. Event Counter

The control bits for event counting are located in register 0Ch. Counter 1 Polarity is bit C1P. bit 0: Counter 2 Polarity is C2P, bit 1; the Cascade Control is CC, bit 2; and the Read Counter bit is RC bit 3.

The polarity bits must be set prior to setting the counter value(s). If a polarity bit is changed, the counter may inadvertently increment. If the counter pins are not being used, tie them to ground.

Serial Number

A memory location to write a 64-bit serial number is provided. It is a writeable nonvolatile memory block that can be locked by the user once the serial number is set. The 8 bytes of data and the lock bit are all accessed via the device ID for the processor companion. Therefore the serial number area is separate and distinct from the memory array. The serial number registers can be written an unlimited number of times, so these locations are general purpose memory. However once the lock bit is set the values cannot be altered and the lock cannot be removed. Once locked the serial number registers can still be read by the system.

The serial number is located in registers 11h to 18h. The lock bit is SNL, register 0Bh bit 7. Setting the SNL bit to a 1 disables writes to the serial number registers, and the SNL bit cannot be cleared.

Backup Power

The event counter and battery-backed registers may be powered with a backup power source. When the primary system power fails, the voltage on the V_{DD} pin will drop. When V_{DD} is less than 2.5V, the event counters and battery-backed registers will switch to the backup power supply on V_{BAK}.

A battery may be inserted into a system board without any concern for excessive current draw on the FM32L27x's V_{BAK} pin.

Trickle Charger

To facilitate capacitor backup the V_{BAK} pin can optionally provide a trickle charge current. When the VBC bit, register 0Bh bit 2, is set to '1', the V_{BAK} pin will source approximately 80 µA until V_{BAK} reaches V_{DD} . This charges the capacitor to V_{DD} without an external diode and resistor charger. There is a Fast Charge mode which is enabled by the FC bit (register 0Bh, bit 5). In this mode the trickle charger current is set to approximately 1 mA, allowing a large backup capacitor to charge more quickly.

In the case where no backup supply is used, the V_{BAK} pin should be tied to VSS. Be sure to turn off the trickle charger (VBC=0), otherwise charger current will be shunted to ground from V_{DD} .

🤁 Note: systems using lithium batteries should clear the VBC bit to 0 to prevent battery charging. The V_{RAK} circuitry includes an internal 1 $K\Omega$ series resistor as a safety element. The trickle charger is UL Recognized.

Register Map

The processor companion functions are accessed via 16 special function registers mapped to a separate 2-wire device ID. The interface protocol is described below. The registers contain timekeeping data, control bits, or information flags. A description of each register follows the summary table below.

Register Map Summary Table

Nonvolatile =	Battery-backed =
1 ton volutile	Buttery bucked

Address	ess D7 D6 D5 D4 D3 D2 D1 D0 Serial Number Byte 7							D0	Function	Range
18h			Serial Number 7	FFh						
17h			Serial Number 6	FFh						
16h			Seria	al Number E	Byte 5				Serial Number 5	FFh
15h			Seria	al Number E	Byte 4				Serial Number 4	FFh
14h			Seria	al Number E	Byte 3				Serial Number 3	FFh
13h			Seria	al Number E	Byte 2				Serial Number 2	FFh
12h			Seria	al Number E	Byte 1				Serial Number 1	FFh
11h			Seria	al Number E	Byte 0				Serial Number 0	FFh
10h			С	ounter 2 MS	SB				Event Counter 2 MSB	FFh
0Fh			C	ounter 2 LS	SB .				Event Counter 2 LSB	FFh
0Eh			С	ounter 1 MS	SB				Event Counter 1 MSB	FFh
0Dh			C	ounter 1 LS	SB				Event Counter 1 LSB	FFh
0Ch					RC	CC	C2P	C1P	Event Count Control	
0Bh	SNL	-	FC	WP1	WP0	VBC	-	VTP	Companion Control	
0Ah	WDE	-	-	WDT4	WDT3	WDT2	WDT1	WDT0	Watchdog Control	
09h	WTR	POR	LB	-	WR3	WR2	WR1	WR0	Watchdog Restart/Flag	S
00-08h				DO NO	T USE				RESERVED	

^{*}Note that the usable address range starts at address 09h to preserve software compatibility with the FM31L27x device family, which includes a real-time clock in registers 00-08h.

Note: When the device is first powered up and programmed, all registers must be written because the battery-backed register values cannot be guaranteed. The table below shows the default values of the non-volatile registers. All other register values should be treated as unknown.

Default Register Values

Address	Hex Value
18h	0x00
17h	0x00
16h	0x00
15h	0x00
14h	0x00
13h	0x00
12h	0x00
11h	0x00
0Bh	0x00
0Ah	0x1F

Register Description

Address Description

18h	Serial Nun	nber Byte 7													
	D7	D6	D5	D4	D3	D2	D1	D0							
	SN.63	SN.62	SN.61	SN.60	SN.59	SN.58	SN.57	SN.56							
		of the serial nur	nber. Read/wri	te when SNL=	0, read-only wh	nen SNL=1. N	onvolatile.								
17h	Serial Nun	ber Byte 6													
	D7	D6	D5	D4	D3	D2	D1	D0							
	SN.55	SN.54	SN.53	SN.52	SN.51	SN.50	SN.49	SN.48							
		serial number.	Read/write wl	nen SNL=0, rea	ad-only when S	SNL=1. Nonvo	olatile.								
16h	Serial Num				r	r		,							
	D7	D6	D5	D4	D3	D2	D1	D0							
	SN.47	SN.46	SN.45	SN.44	SN.43	SN.42	SN.41	SN.40							
		yte 5 of the serial number. Read/write when SNL=0, read-only when SNL=1. Nonvolatile.													
15h		iber Byte 4	1	1	T	I		T							
	D7	D6	D5	D4	D3	D2	D1	D0							
	SN.39	SN.38	SN.37	SN.36	SN.35	SN.34	SN.33	SN.32							
		Byte 4 of the serial number. Read/write when SNL=0, read-only when SNL=1. Nonvolatile.													
14h	Serial Num	,													
	D7	D6	D5	D4	D3	D2	D1	D0							
	SN.31	SN.30	SN.29	SN.28	SN.27	SN.26	SN.25	SN.24							
	Byte 3 of the	serial number.	Read/write wl	nen SNL=0, rea	ad-only when S	SNL=1. Nonvo	latile.								
13h	Serial Num	iber Byte 2													
	D7	D6	D5	D4	D3	D2	D1	D0							
	SN.23	SN.22	SN.21	SN.20	SN.19	SN.18	SN.17	SN.16							
								21,110							
12h	Byte 2 of the serial number. Read/write when SNL=0, read-only when SNL=1. Nonvolatile. Serial Number Byte 1														
	D7	D6	D5	D4	D3	D2	D1	D0							
	υ/	סט	טט	D4	DS	D2	<i>D</i> 1	DU							
	SN.15	SN.14	SN.13	SN.12	SN.11	SN.10	SN.9								
	SN.15		SN.13	SN.12	SN.11	SN.10	SN.9	SN.8							
11h	SN.15	SN.14 serial number.	SN.13	SN.12	SN.11	SN.10	SN.9								
11h	SN.15 Byte 1 of the	SN.14 serial number.	SN.13	SN.12	SN.11	SN.10	SN.9								
11h	SN.15 Byte 1 of the Serial Num D7	SN.14 e serial number ber Byte 0 D6	SN.13 Read/write wl	SN.12 hen SNL=0, rea	SN.11 ad-only when S	SN.10 SNL=1. Nonvo	SN.9 latile.	SN.8 D0							
11h	SN.15 Byte 1 of the Serial Num D7 SN.7	SN.14 e serial number.	SN.13 Read/write wl D5 SN.5	SN.12 nen SNL=0, rea D4 SN.4	SN.11 ad-only when S D3 SN.3	SN.10 SNL=1. Nonvo	SN.9 slatile.	SN.8							
11h	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the serial states and the serial states are serial state	SN.14 e serial number. ber Byte 0 D6 SN.6 erial number. R	SN.13 Read/write wl D5 SN.5	SN.12 nen SNL=0, rea D4 SN.4	SN.11 ad-only when S D3 SN.3	SN.10 SNL=1. Nonvo	SN.9 slatile.	SN.8 D0							
	SN.15 Byte 1 of the Serial Num D7 SN.7	SN.14 e serial number. ber Byte 0 D6 SN.6 erial number. R	SN.13 Read/write wl D5 SN.5	SN.12 nen SNL=0, rea D4 SN.4	SN.11 ad-only when S D3 SN.3	SN.10 SNL=1. Nonvo	SN.9 slatile.	SN.8 D0							
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	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2 D7 C2.15	SN.14 e serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13	SN.12 nen SNL=0, rea D4 SN.4 n SNL=0, read D4 C2.12	SN.11 ad-only when S D3 SN.3 -only when SN D3 C2.11	SN.10 SNL=1. Nonvo D2 SN.2 IL=1. Nonvola D2 C2.10	SN.9 slatile. D1 SN.1 tile. D1 C2.9	SN.8 D0 SN.0							
10h	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2 D7 C2.15 Event Count	SN.14 e serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incr	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13	SN.12 nen SNL=0, rea D4 SN.4 n SNL=0, read D4 C2.12	SN.11 ad-only when S D3 SN.3 -only when SN D3 C2.11	SN.10 SNL=1. Nonvo D2 SN.2 IL=1. Nonvola D2 C2.10	SN.9 slatile. D1 SN.1 tile. D1 C2.9	SN.8 D0 SN.0							
	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2 D7 C2.15	SN.14 e serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incr	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13	SN.12 nen SNL=0, rea D4 SN.4 n SNL=0, read D4 C2.12	SN.11 ad-only when S D3 SN.3 -only when SN D3 C2.11	SN.10 SNL=1. Nonvo D2 SN.2 IL=1. Nonvola D2 C2.10	SN.9 slatile. D1 SN.1 tile. D1 C2.9	SN.8 D0 SN.0							
10h	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the se Counter 2 D7 C2.15 Event Counter Counter 2 D7	SN.14 e serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incr LSB D6	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13 ements on over	SN.12 hen SNL=0, read D4 SN.4 n SNL=0, read D4 C2.12 rflows from Co	SN.11 ad-only when S D3 SN.3 -only when SN D3 C2.11 unter 2 LSB. E	SN.10 SNL=1. Nonvo D2 SN.2 IL=1. Nonvola D2 C2.10 Battery-backed	SN.9 latile. D1 SN.1 tile. D1 C2.9 , read/write.	D0 SN.0 D0 C2.8							
10h	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the se Counter 2 D7 C2.15 Event Counter Counter 2 D7 C2.7	SN.14 e serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incr LSB D6 C2.6	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13 ements on over	SN.12 hen SNL=0, read D4 SN.4 n SNL=0, read D4 C2.12 rflows from Co	SN.11 ad-only when S D3 SN.3 -only when SN D3 C2.11 unter 2 LSB. E D3 C2.3	SN.10 SNL=1, Nonvo D2 SN.2 IL=1, Nonvola D2 C2.10 Battery-backed D2 C2.2	SN.9 latile. D1 SN.1 tile. D1 C2.9 , read/write. D1 C2.1	D0 SN.0 D0 C2.8 D0 C2.0							
10h	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the serial Counter 2 D7 C2.15 Event Counter 2 D7 C2.7 Event Counter 2	SN.14 e serial number. hber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incre LSB C2.6 er 2 LSB. Incre	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13 ements on over	SN.12 hen SNL=0, read D4 SN.4 n SNL=0, read D4 C2.12 rflows from Co	SN.11 ad-only when S D3 SN.3 -only when SN D3 C2.11 unter 2 LSB. E D3 C2.3	SN.10 SNL=1, Nonvo D2 SN.2 IL=1, Nonvola D2 C2.10 Battery-backed D2 C2.2	SN.9 latile. D1 SN.1 tile. D1 C2.9 , read/write. D1 C2.1	D0 SN.0 D0 C2.8 D0 C2.0							
10h	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the serial Counter 2: D7 C2.15 Event Counter 2: D7 C2.7 Event Counter 4: Event Counter 5: Event Counter 6: Event Counter 6: Event Counter 7: Event Counter 8: Event Counter 8: Event Counter 9: Event	SN.14 e serial number. hber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incre LSB C2.6 er 2 LSB. Incre Battery-backet	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13 ements on over	SN.12 hen SNL=0, read D4 SN.4 n SNL=0, read D4 C2.12 rflows from Co	SN.11 ad-only when S D3 SN.3 -only when SN D3 C2.11 unter 2 LSB. E D3 C2.3	SN.10 SNL=1, Nonvo D2 SN.2 IL=1, Nonvola D2 C2.10 Battery-backed D2 C2.2	SN.9 latile. D1 SN.1 tile. D1 C2.9 , read/write. D1 C2.1	D0 SN.0 D0 C2.8 D0 C2.0							
10h 0Fh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the serial Counter 2 D7 C2.15 Event Counter 2 D7 C2.7 Event Counter 2	SN.14 e serial number. hber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incre LSB C2.6 er 2 LSB. Incre Battery-backet	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13 ements on over	SN.12 hen SNL=0, read D4 SN.4 n SNL=0, read D4 C2.12 rflows from Co	SN.11 ad-only when S D3 SN.3 -only when SN D3 C2.11 unter 2 LSB. E D3 C2.3	SN.10 SNL=1, Nonvo D2 SN.2 IL=1, Nonvola D2 C2.10 Battery-backed D2 C2.2	SN.9 latile. D1 SN.1 tile. D1 C2.9 , read/write. D1 C2.1	D0 SN.0 D0 C2.8 D0 C2.0							
10h 0Fh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the se Counter 2 D7 C2.15 Event Counter 2 D7 C2.7 Event Counter 2 D7 C2.7 Event Counter 2 Tounter 1 D7	SN.14 e serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incr LSB D6 C2.6 er 2 LSB. Incre Battery-backer MSB D6	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13 ements on over D5 C2.5 ements on prog d, read/write .	SN.12 hen SNL=0, read D4 SN.4 n SNL=0, read D4 C2.12 rflows from Co D4 C2.4 rammed edge e	SN.11 ad-only when S D3 SN.3 -only when SN D3 C2.11 unter 2 LSB. E D3 c2.3 event on CNT2	SN.10 SNL=1. Nonvo D2 SN.2 IL=1. Nonvola D2 C2.10 Battery-backed D2 C2.2 input or overf	SN.9 latile. D1 SN.1 tile. D1 C2.9 , read/write. D1 C2.1 lows from Cou	D0 SN.0 D0 C2.8 D0 C2.0 nter 1 MSB							
10h 0Fh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the se Counter 2 D7 C2.15 Event Counter 2 D7 C2.7 Event Counter 1 Counter 1 D7 C1.15	SN.14 e serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incr LSB D6 C2.6 er 2 LSB. Incre Battery-backet MSB D6 C1.14	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13 ements on over D5 C2.5 ements on prog d, read/write . D5 C1.13	SN.12 hen SNL=0, read SN.4 n SNL=0, read D4 C2.12 rflows from Co D4 C2.4 rammed edge e	SN.11 ad-only when S D3 SN.3 -only when SN D3 C2.11 unter 2 LSB. E D3 C2.3 event on CNT2 D3 C1.11	SN.10 SNL=1. Nonvo D2 SN.2 IL=1. Nonvola D2 C2.10 Battery-backed D2 C2.2 input or overf	SN.9 latile. D1 SN.1 tile. D1 C2.9 , read/write. D1 C2.1 lows from Cou	D0 SN.0 D0 C2.8 D0 C2.0 nter 1 MSB							
10h OFh OEh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the se Counter 2 D7 C2.15 Event Counter 2 D7 C2.7 Event Counter 4 Counter 1 D7 C1.15 Event Counter 1 Event Counter 1	SN.14 e serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incr LSB D6 C2.6 er 2 LSB. Incre Battery-backer MSB D6 C1.14 er 1 MSB. Incr	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13 ements on over D5 C2.5 ements on prog d, read/write . D5 C1.13	SN.12 hen SNL=0, read SN.4 n SNL=0, read D4 C2.12 rflows from Co D4 C2.4 rammed edge e	SN.11 ad-only when S D3 SN.3 -only when SN D3 C2.11 unter 2 LSB. E D3 C2.3 event on CNT2 D3 C1.11	SN.10 SNL=1. Nonvo D2 SN.2 IL=1. Nonvola D2 C2.10 Battery-backed D2 C2.2 input or overf	SN.9 latile. D1 SN.1 tile. D1 C2.9 , read/write. D1 C2.1 lows from Cou	D0 SN.0 D0 C2.8 D0 C2.0 nter 1 MSB							
10h 0Fh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the Serial Serial Num D7 SN.7 LSB of the Serial	SN.14 e serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incre LSB D6 c2.6 er 2 LSB. Incre Battery-backer MSB D6 C1.14 er 1 MSB. Incre LSB	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13 ements on over D5 C2.5 ements on prog d, read/write . D5 C1.13 ements on over	SN.12 hen SNL=0, read SN.4 n SNL=0, read D4 C2.12 rflows from Co D4 C2.4 rammed edge e	SN.11 ad-only when S D3 SN.3 -only when SN D3 C2.11 unter 2 LSB. E D3 C2.3 event on CNT2 D3 C1.11 unter 1 LSB. E	SN.10 SNL=1. Nonvo D2 SN.2 IL=1. Nonvola D2 C2.10 Battery-backed D2 C2.2 input or overf D2 C1.10 Battery-backed	SN.9 latile. D1 SN.1 tile. D1 C2.9 read/write. D1 C2.1 lows from Cou	D0 SN.0 D0 C2.8 D0 C2.0 nter 1 MSB							
10h OFh OEh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the se Counter 2 D7 C2.15 Event Counter 2 D7 C2.7 Event Counter 1 D7 C1.15 Event Counter 1 D7 C1.15 Event Counter 1 D7	SN.14 e serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incre LSB D6 C2.6 er 2 LSB. Incre Battery-backer MSB D6 C1.14 er 1 MSB. Incre LSB D6 C1.14	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13 ements on over D5 C2.5 ements on prog d, read/write . D5 C1.13 ements on over	SN.12 hen SNL=0, read D4 SN.4 n SNL=0, read D4 C2.12 rflows from Co D4 C2.4 rammed edge 6 D4 C1.12 rflows from Co	SN.11 ad-only when S D3 SN.3 -only when SN D3 C2.11 unter 2 LSB. E D3 C2.3 event on CNT2 D3 C1.11 unter 1 LSB. E	SN.10 SNL=1. Nonvo D2 SN.2 IL=1. Nonvola D2 C2.10 Battery-backed D2 C2.2 input or overf D2 C1.10 Battery-backed	SN.9 latile. D1 SN.1 tile. D2.9 read/write. D1 C2.1 lows from Cou D1 C1.9 read/write.	D0 SN.0 D0 C2.8 D0 C2.0 nter 1 MSB D0 C1.8							
10h OFh OEh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the se Counter 2 D7 C2.15 Event Counter 2 D7 C2.7 Event Counter 1 D7 C1.15 Event Counter 1 D7 C1.15 Event Counter 1 D7 C1.7	SN.14 e serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incre LSB D6 c2.6 er 2 LSB. Incre Battery-backer MSB D6 C1.14 er 1 MSB. Incre LSB	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13 ements on over D5 C2.5 ements on prog d, read/write . D5 C1.13 ements on over	SN.12 hen SNL=0, read D4 SN.4 n SNL=0, read D4 C2.12 rflows from Co D4 C2.4 rammed edge e D4 C1.12 rflows from Co	D3 SN.3 -only when SN D3 C2.11 unter 2 LSB. E D3 C2.3 event on CNT2 D3 C1.11 unter 1 LSB. E D3 C1.3	SN.10 SNL=1. Nonvo D2 SN.2 IL=1. Nonvola D2 C2.10 Battery-backed D2 C2.2 input or overf D2 C1.10 Battery-backed	SN.9 latile. D1 SN.1 tile. D2.9 read/write. D1 C2.1 lows from Cou D1 C1.9 read/write. D1 C1.9 C1.1	D0 SN.0 D0 C2.8 D0 C2.0 nter 1 MSB D0 C1.8							

0Ch	Event Co	unter Contr	ol										
1	D7	D6	D5	D4	D3	D2	D1	D 0					
	_	_	_	_	RC	CC	C2P	C1P					
RC	Read Coun	iter. Setting th	is bit to 1 takes	a snapshot of tl									
				e RC bit will be			-						
CC				nt counters oper									
				, the counters at 16-bits of the c									
			. Battery-backe		ounter and CN	i is the confic	ming mput. Di	CZF IS					
C2P				0, rising edges	when $C2P = 1$.	C2P is "don't	care" when CC	C=1. The value					
				crement if C2P									
C1P	CNT1 detects falling edges when C1P = 0, rising edges when C1P = 1. The value of Event Counter 1 may inadvertently increment if C1P is changed. Battery-backed, read/write.												
ADL	inadvertently increment if C1P is changed. Battery-backed, read/write. Companion Control												
0Bh	Compani D7	D6	D5	D4	D3	D2	D1	D0					
		DU					DI						
SNL	SNL Social Num	har Laak Sat	FC	WP1 es registers 11h	WP0	VBC	road only CN	VTP					
SNL			onvolatile, reac		to Toll allu SIN	L permanently	read-only. Six.	L cannot be					
FC	Fast Charg	e: Setting FC	to '1' (and VB	C=1) causes a ~	-1 mA trickle cl	harge current to	be supplied or	n V _{BAK} .					
				current. Nonvo									
WP1-0	Write Prote	ect. These bits	control the wri	te protection of	the memory ar	ray. Nonvolatil	e, read/write.						
	,	Write protect	addresses	WP1 WP0									
	_	None	uddiesses	0 0									
		Bottom 1/4		0 1									
	F	Bottom 1/2		1 0									
		Full array		1 1									
VBC				o '1' (and FC=0				arge current to					
VTP1-0				0' disables the ip point for the				rita					
V 11 1-0	VII SCIECT	This on com	iois the reset th	ip point for the	iow v DD Teset	Tunetion. Nonv	oratrie, read/w	IIIC.					
	1												
	Trip Voltage VTP												
	<u> </u>	2.6V	<u>VTP</u> 0										
		2.6V 2.9V											
0Ah	Watchdo	2.6V 2.9V g Control	0										
0Ah		2.6V 2.9V		D4	D3	D2	D1	D0					
	Watchdo D7	2.6V 2.9V g Control D6	0 1 D5	WDT4	WDT3	WDT2	WDT1	WDT0					
0Ah WDE	Watchdo D7 WDE Watchdog	2.6V 2.9V g Control D6	0 1 D5 - WDE=1, a wa	WDT4 tchdog timer far	WDT3 ult will cause th	WDT2 ne /RST signal t	WDT1 to go active. W	WDT0 hen WDE = 0					
	Watchdo D7 WDE Watchdog the timer re	2.6V 2.9V g Control D6 Enable. When	0 1 D5 - WDE=1, a wa' effect on /RST	WDT4 tchdog timer far , however the V	WDT3 ult will cause the	WDT2 ne /RST signal to a set when a far	WDT1 to go active. W ult occurs. Not	WDT0 hen WDE = 0 e as the timer					
WDE	Watchdo D7 WDE Watchdog the timer ruis free-runt timeout int	2.6V 2.9V g Control D6 Enable. When ans but has no ning, users sho erval occurs. N	0 1 D5 	WDT4 tchdog timer far t, however the V timer using WR ad/write.	WDT3 ult will cause the VTR flag will be 3-0 prior to sett	WDT2 The /RST signal to a set when a facting WDE=1. The set when a facting wde=1.	WDT1 to go active. W ult occurs. Not this assures a fu	wDT0 hen WDE = 0 e as the timer all watchdog					
	Watchdo D7 WDE Watchdog the timer ruis free-runt timeout int Watchdog	2.6V 2.9V g Control D6 Enable. When cans but has no ning, users sho erval occurs. It Timeout. Indicates the control of the control occurs. It is not the con	D5 WDE=1, a war effect on /RST ould restart the to Nonvolatile, reacates the minim	WDT4 tchdog timer far the Words with the Words timer using WR d/write. tum watchdog t	WDT3 ult will cause the VTR flag will b 3-0 prior to settimeout interval	WDT2 with 100 ms re	WDT1 to go active. W ult occurs. Not his assures a fu	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					
WDE	Watchdo D7 WDE Watchdog the timer ruis free-runt timeout int Watchdog	2.6V 2.9V g Control D6 Enable. When cans but has no ning, users sho erval occurs. It Timeout. Indicates the control of the control occurs. It is not the con	D5 WDE=1, a war effect on /RST ould restart the to Nonvolatile, reacates the minim	WDT4 tchdog timer far t, however the V timer using WR ad/write.	WDT3 ult will cause the VTR flag will b 3-0 prior to settimeout interval	WDT2 with 100 ms re	WDT1 to go active. W ult occurs. Not his assures a fu	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					
WDE	Watchdo D7 WDE Watchdog the timer ruis free-runt timeout int Watchdog timeouts an	2.6V 2.9V g Control D6 Enable. When ans but has no ning, users sho erval occurs. Timeout. Indicate loaded when	D5 WDE=1, a wareffect on /RST ould restart the toon volatile, reacates the miniman the timer is resulted.	WDT4 tchdog timer far the Vitimer using WR ad/write. tum watchdog t started by writing	WDT3 ult will cause the VTR flag will be 3-0 prior to sette imeout intervaling the 1010b page.	WDT2 ne /RST signal to e set when a facting WDE=1. To with 100 ms reattern to WR3-0	WDT1 to go active. W ult occurs. Not his assures a fu esolution. New D. Nonvolatile,	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					
WDE	Watchdo D7 WDE Watchdog the timer ruis free-runi timeout int Watchdog timeouts ar	2.6V 2.9V g Control D6 Enable. When ans but has no ning, users sho erval occurs. Timeout. Indice loaded wher	D5 WDE=1, a wa effect on /RST ould restart the to Nonvolatile, reacates the minima the timer is remeout	WDT4 tchdog timer far , however the V timer using WR ad/write. hum watchdog t started by writi WDT4 W	WDT3 ult will cause the VTR flag will be 3-0 prior to sette imeout intervaling the 1010b part of the VDT3 WDT2	WDT2 ne /RST signal to e set when a facting WDE=1. To with 100 ms reattern to WR3-0	WDT1 to go active. W ult occurs. Not this assures a fu esolution. New D. Nonvolatile,	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					
WDE	Watchdo D7 WDE Watchdog the timer ru is free-runt timeout int Watchdog timeouts ar	2.6V 2.9V g Control D6 Enable. When ans but has no ning, users sho erval occurs. Timeout. Indicate loaded when	D5 WDE=1, a wa effect on /RST ould restart the to Nonvolatile, reacates the minima the timer is remeout	WDT4 tchdog timer far the Vitimer using WR ad/write. tum watchdog t started by writing	WDT3 ult will cause the VTR flag will be 3-0 prior to sette imeout intervaling the 1010b part of the VDT3 WDT2	wDT2 ne /RST signal to e set when a farting WDE=1. To with 100 ms reattern to WR3-0 WDT1 WDT	WDT1 to go active. W ult occurs. Not this assures a fu esolution. New D. Nonvolatile,	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					
WDE	Watchdo D7 WDE Watchdog the timer ru is free-runt timeout int Watchdog timeouts ar	2.6V 2.9V g Control D6 Enable. When uns but has no ning, users sho erval occurs. National occurs are loaded when watchdog timenvalid – defa	D5 WDE=1, a wa effect on /RST ould restart the to Nonvolatile, reacates the minima the timer is remeout	WDT4 tchdog timer fai t, however the V timer using WR ad/write. hum watchdog t estarted by writing WDT4 W 0	WDT3 ult will cause the VTR flag will be 3-0 prior to set	wDT2 with 100 ms restricted to WR3-0 WDT1 WDT WDT1 WDT O O	WDT1 to go active. W ult occurs. Not his assures a fu esolution. New D. Nonvolatile,	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					
WDE	Watchdo D7 WDE Watchdog the timer ruis free-runt timeout int Watchdog timeouts ar Value 1	2.6V 2.9V g Control D6	D5 WDE=1, a wa effect on /RST ould restart the to Nonvolatile, reacates the minima the timer is remeout	WDT4 tchdog timer far thowever the V timer using WR ad/write. num watchdog t estarted by writing WDT4 W 0 0	WDT3 ult will cause the VTR flag will be 3-0 prior to set	wDT2 we /RST signal to the set when a facting WDE=1. To with 100 ms restricted to WR3-0 WDT1 WDT 0 0 0 1	WDT1 to go active. W ult occurs. Not his assures a fu esolution. New). Nonvolatile,	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					
WDE	Watchdo D7 WDE Watchdog the timer ruis free-runt timeout int Watchdog timeouts ar Value 1	2.6V 2.9V g Control D6 Enable. When ans but has no ning, users sho erval occurs. I Timeout. Indie e loaded wher Watchdog tim nvalid – defa 00 ms	D5 WDE=1, a wa effect on /RST ould restart the to Nonvolatile, reacates the minima the timer is remeout	WDT4 tchdog timer far t, however the V timer using WR ad/write. tum watchdog t estarted by writing WDT4 W 0 0 0	WDT3 ult will cause the VTR flag will be 3-0 prior to set	wDT2 we /RST signal to the set when a facting WDE=1. The with 100 ms restricted to WR3-0 WDT1 WDT 0 0 0 1 1 0	WDT1 to go active. W ult occurs. Not his assures a fu esolution. New). Nonvolatile,	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					
WDE	Watchdo D7 WDE Watchdog the timer rule is free-runt timeout int Watchdog timeouts ar U I I I I I I I I I I I I I I I I I I	2.6V 2.9V g Control D6 Enable. When uns but has no ning, users sho erval occurs. I Timeout. Indice te loaded when Watchdog tim nvalid – defa 00 ms 000 ms	D5 WDE=1, a wa effect on /RST ould restart the to Nonvolatile, reacates the minima the timer is remeout	WDT4 tchdog timer far t, however the V timer using WR ad/write. tum watchdog t estarted by writing WDT4 W 0 0 0	wDT3 ult will cause the VTR flag will be 3-0 prior to settle imeout intervaling the 1010b part of the	wDT2 we /RST signal to the set when a facting WDE=1. The with 100 ms restricted to WR3-0 WDT1 WDT 0 0 0 1 1 0	wDT1 to go active. W ult occurs. Not this assures a fu esolution. New). Nonvolatile,	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					
WDE	Watchdo D7 WDE Watchdog the timer ruis free-runt timeout int Watchdog timeouts ar Value of the timer of the time of the time of the time out int Watchdog timeouts ar 2 3	2.6V 2.9V g Control D6 Enable. When ans but has no ning, users sho erval occurs. I Timeout. Indie e loaded wher Watchdog tim nvalid – defa 00 ms	D5 WDE=1, a wa effect on /RST ould restart the to Nonvolatile, reacates the minima the timer is remeout	WDT4 tchdog timer far t, however the V timer using WR ad/write. tum watchdog t estarted by writing WDT4 W 0 0 0 0	WDT3 ult will cause the VTR flag will be 3-0 prior to set to 3-0 prior to 3-0 prior to set to 3-0 prior to	wDT2 we /RST signal to e set when a facting WDE=1. To with 100 ms reattern to WR3-0 WDT1 WDT 0 0 0 1 1 0 1 1	wDT1 to go active. W ult occurs. Not his assures a fu esolution. New Nonvolatile,	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					
WDE	Watchdo D7 WDE Watchdog the timer ruis free-runi timeout int Watchdog timeouts ar Value of the timer are in timeout interpretation of the timer are in the time are in timeout in timeout are in timeo	2.6V 2.9V g Control D6 Enable. When ans but has no ning, users sho erval occurs. N Timeout. Indie e loaded when Watchdog tim nvalid – defa 00 ms 200 ms 600 ms	D5 WDE=1, a wa effect on /RST ould restart the to Nonvolatile, reacates the minima the timer is remeout	WDT4 tchdog timer far t, however the V timer using WR ad/write. tum watchdog t estarted by writi WDT4 W 0 0 0 0 0	wDT3 ult will cause the VTR flag will be 3-0 prior to set to set to 3-0 prior t	wDT2 te /RST signal te set when a fatting WDE=1. The with 100 ms restricted to WR3-0 WDT1 WDT 0 0 1 1 0 1 1 0 0 0 1	wDT1 to go active. W ult occurs. Not his assures a fu esolution. New Nonvolatile,	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					
WDE	Watchdo D7 WDE Watchdog the timer ruis free-runi timeout int Watchdog timeouts ar Value of the timer are in timeout interpretation of the timer are in the time are in timeout in timeout are in timeo	2.6V 2.9V g Control D6 Enable. When ans but has no ning, users sho erval occurs. I Timeout. Indice loaded when Watchdog tim nvalid – defa 00 ms 200 ms 100 ms 100 ms 1000 ms	D5 WDE=1, a wa effect on /RST ould restart the to Nonvolatile, reacates the minima the timer is remeout	WDT4 tchdog timer far t, however the V timer using WR ad/write. tum watchdog t estarted by writing WDT4 W 0 0 0 1 1	wDT3 ult will cause the VTR flag will be 3-0 prior to set of the set of the volume of the volu	WDT2 ne /RST signal to e set when a facting WDE=1. To with 100 ms reattern to WR3-0 WDT1 WDT 0 0 1 1 0 1 1 0 0 0 1 1 0 1 1	wDT1 to go active. W ult occurs. Not his assures a fu esolution. New Nonvolatile,	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					
WDE	Watchdo D7 WDE Watchdog the timer ruis free-runt timeout int Watchdog timeouts ar Value 1 2 3 2 2 2 2	2.6V 2.9V g Control D6 Enable. When ans but has no ning, users sho erval occurs. N Timeout. Indie e loaded when Watchdog tim nvalid – defa 00 ms 200 ms 100 ms 1100 ms 1200 ms	D5 WDE=1, a wa effect on /RST ould restart the to Nonvolatile, reacates the minima the timer is remeout	WDT4 tchdog timer far t, however the V timer using WR ad/write. tum watchdog t estarted by writing WDT4 W 0 0 0 1 1	wDT3 ult will cause the VTR flag will be 3-0 prior to set of the set of the volume of the volu	WDT2 ne /RST signal to e set when a facting WDE=1. The with 100 ms restricted to WR3-0 WDT1 WDT	wDT1 to go active. W ult occurs. Not his assures a fu esolution. New Nonvolatile,	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					
WDE	Watchdo D7 WDE Watchdog the timer ruis free-runitimeout int Watchdog timeouts ar Vatchdog timeouts ar 2 2 2 2 2 2	2.6V 2.9V g Control D6 Enable. When ans but has no ning, users sho erval occurs. I Timeout. Indice loaded when Watchdog tim nvalid – defa 00 ms 200 ms 100 ms 100 ms 1000 ms	D5 WDE=1, a wa effect on /RST ould restart the to Nonvolatile, reacates the minima the timer is remeout	WDT4 tchdog timer far t, however the V timer using WR ad/write. tum watchdog t estarted by writing WDT4 W 0 0 0 1 1	wDT3 ult will cause the VTR flag will be 3-0 prior to set of the set of the volume of the volu	WDT2 ne /RST signal to e set when a facting WDE=1. To with 100 ms reattern to WR3-0 WDT1 WDT 0 0 1 1 0 1 1 0 0 0 1 1 0 1 1	wDT1 to go active. W ult occurs. Not his assures a fu esolution. New Nonvolatile,	wDT0 hen WDE = 0 e as the timer ull watchdog watchdog					

09h	Watchdo	g Restart &	Flags								
	D7	D6	D5	D4	D3	D2	D1	D0			
	WTR POR LB - WR3 WR2 WR1										
WTR	by the user	. Note that bo	th WTR and PC	atchdog timer fa OR could be set ad/Write (intern	if both reset so	urces have occu					
POR	set to 1. It	must be cleare	d by the user. N	n is activated b Note that both W the user. Batter	TR and POR o	ould be set if b	oth reset source	es have			
LB	this bit will		he user should	BAK source is clear it to 0 who		•					
WR3-0	not affect t	his operation.	Writing any pa	10b to WR3-0 attern other that ags without affects	n 1010b to WR	3-0 has no eff	ect on the time	r. This allows			

Reserved – DO NOT USE THIS ADDRESS SPACE 00-08h

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Two-wire Interface

The FM32L27x employs an industry standard two-wire bus that is familiar to many users. This product is unique since it incorporates two logical devices in one chip. Each logical device can be accessed individually. Although monolithic, it appears to the system software to be two separate products. One is a memory device. It has a Slave Address (Slave ID = 1010b) that operates the same as a stand-alone memory device. The second device is a real-time clock and processor companion which have a unique Slave Address (Slave ID = 1101b).

By convention, any device that is sending data onto the bus is the transmitter while the target device for this data is the receiver. The device that is controlling the bus is the master. The master is responsible for generating the clock signal for all operations. Any device on the bus that is being controlled is a slave. The FM32L27x is always a slave device.

The bus protocol is controlled by transition states in the SDA and SCL signals. There are four conditions: Start, Stop, Data bit, and Acknowledge. The figure below illustrates the signal conditions that specify the four states. Detailed timing diagrams are shown in the Electrical Specifications section.

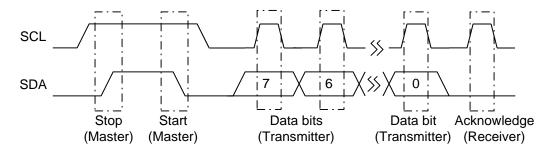


Figure 9. Data Transfer Protocol

Start Condition

A Start condition is indicated when the bus master drives SDA from high to low while the SCL signal is high. All read and write transactions begin with a Start condition. An operation in progress can be aborted by asserting a Start condition at any time. Aborting an operation using the Start condition will ready the FM32L27x for a new operation.

If the power supply drops below the specified VTP during operation, any 2-wire transaction in progress will be aborted and the system must issue a Start condition prior to performing another operation.

Stop Condition

A Stop condition is indicated when the bus master drives SDA from low to high while the SCL signal is high. All operations must end with a Stop condition. If an operation is pending when a stop is asserted, the operation will be aborted. The master must have control of SDA (not a memory read) in order to assert a Stop condition.

Data/Address Transfer

All data transfers (including addresses) take place while the SCL signal is high. Except under the two conditions described above, the SDA signal should not change while SCL is high.

Acknowledge

The Acknowledge (ACK) takes place after the 8th data bit has been transferred in any transaction. During this state the transmitter must release the SDA bus to allow the receiver to drive it. The receiver drives the SDA signal low to acknowledge receipt of the byte. If the receiver does not drive SDA low, the condition is a No-Acknowledge (NACK) and the operation is aborted.

The receiver might NACK for two distinct reasons. First is that a byte transfer fails. In this case, the NACK ends the current operation so that the part can be addressed again. This allows the last byte to be recovered in the event of a communication error.

Second and most common, the receiver does not send an ACK to deliberately terminate an operation. For example, during a read operation, the FM32L27x will continue to place data onto the bus as long as the receiver sends ACKs (and clocks). When a read operation is complete and no more data is needed, the receiver must NACK the last byte. If the receiver ACKs the last byte, this will cause the FM32L27x to attempt to drive the bus on the next clock while the master is sending a new command such as a Stop.

Slave Address

The first byte that the FM32L27x expects after a Start condition is the slave address. As shown in figures below, the slave address contains the Slave ID, Device Select address, and a bit that specifies if the transaction is a read or a write.

The FM32L27x has two Slave Addresses (Slave IDs) associated with two logical devices. To access the memory device, bits 7-4 should be set to 1010b. The other logical device within the FM32L27x is the real-time clock and companion. To access this device, bits 7-4 of the slave address should be set to 1101b. A bus transaction with this slave address will not affect the memory in any way. The figures below illustrate the two Slave Addresses.

The Device Select bits allow multiple devices of the same type to reside on the 2-wire bus. The device select bits (bits 2-1) select one of four parts on a two-wire bus. They must match the corresponding value on the external address pins in order to select the device. Bit 0 is the read/write bit. A "1" indicates a read operation, and a "0" indicates a write operation.

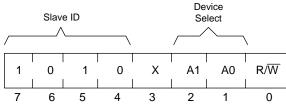


Figure 10. Slave Address - Memory

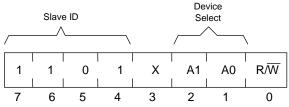


Figure 11. Slave Address - Companion

Addressing Overview - Memory

After the FM32L27x acknowledges the Slave Address, the master can place the memory address on the bus for a write operation. The address requires two bytes. This is true for all members of the family. Therefore the 4Kb and 16Kb configurations will be addressed differently from stand alone serial memories but the entire family will be upwardly compatible with no software changes.

The first is the MSB (upper byte). For a given density unused address bits are don't cares, but should be set to 0 to maintain upward compatibility.

Following the MSB is the LSB (lower byte) which contains the remaining eight address bits. The address is latched internally. Each access causes the latched address to be incremented automatically. The current address is the value that is held in the latch, either a newly written value or the address following the last access. The current address will be held as long as VDD > VTP or until a new value is written. Accesses to the clock do not affect the current memory address. Reads always use the current address. A random read address can be loaded by beginning a write operation as explained below.

After transmission of each data byte, just prior to the Acknowledge, the FM32L27x increments the internal address. This allows the next sequential byte to be accessed with no additional addressing externally. After the last address is reached, the address latch will roll over to 0000h. There is no limit to the number of bytes that can be accessed with a single read or write operation.

Addressing Overview - Companion

The RTC and Processor Companion operate in a similar manner to the memory, except that it uses only one byte of address. Addresses 00h to 18h correspond to special function registers. Attempting to load addresses above 18h is an illegal condition; the FM32L27x will return a NACK and abort the 2-wire transaction.

Data Transfer

After the address information has been transmitted, data transfer between the bus master and the FM32L27x begins. For a read, the FM32L27x will place 8 data bits on the bus then wait for an ACK from the master. If the ACK occurs, the FM32L27x will transfer the next byte. If the ACK is not sent, the FM32L27x will end the read operation. For a write operation, the FM32L27x will accept 8 data bits from the master then send an Acknowledge. All data transfer occurs MSB (most significant bit) first.

Memory Write Operation

All memory writes begin with a Slave Address, then a memory address. The bus master indicates a write operation by setting the slave address LSB to a 0. After addressing, the bus master sends each byte of data to the memory and the memory generates an Acknowledge condition. Any number of sequential bytes may be written. If the end of the address range is reached internally, the address counter will wrap to 0000h. Internally, the actual memory write occurs after the 8th data bit is transferred. It will be complete before the Acknowledge is sent. Therefore, if the

user desires to abort a write without altering the memory contents, this should be done using a Start or Stop condition prior to the 8th data bit. The figures

below illustrate a single- and multiple-writes to memory.

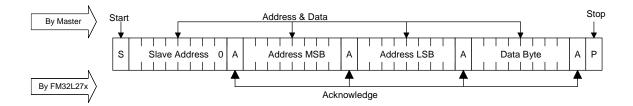


Figure 12. Single Byte Memory Write

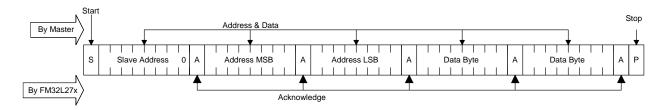


Figure 13. Multiple Byte Memory Write

Memory Read Operation

There are two types of memory read operations. They are current address read and selective address read. In a current address read, the FM32L27x uses the internal address latch to supply the address. In a selective read, the user performs a procedure to first set the address to a specific value.

Current Address & Sequential Read

As mentioned above the FM32L27x uses an internal latch to supply the address for a read operation. A current address read uses the existing value in the address latch as a starting place for the read operation. The system reads from the address immediately following that of the last operation.

To perform a current address read, the bus master supplies a slave address with the LSB set to 1. This indicates that a read operation is requested. After receiving the complete device address, the FM32L27x will begin shifting data out from the current address on the next clock. The current address is the value held in the internal address latch.

Beginning with the current address, the bus master can read any number of bytes. Thus, a sequential read is simply a current address read with multiple byte transfers. After each byte the internal address counter will be incremented.

Each time the bus master acknowledges a byte, this indicates that the FM32L27x should read out the next sequential byte.

There are four ways to terminate a read operation. Failing to properly terminate the read will most likely create a bus contention as the FM32L27x attempts to read out additional data onto the bus. The four valid methods follow.

- 1. The bus master issues a NACK in the 9th clock cycle and a Stop in the 10th clock cycle. This is illustrated in the diagrams below and is preferred.
- 2. The bus master issues a NACK in the 9th clock cycle and a Start in the 10th.
- 3. The bus master issues a Stop in the 9th clock cycle.
- 4. The bus master issues a Start in the 9th clock cycle.

If the internal address reaches the top of memory, it will wrap around to 0000h on the next read cycle. The figures below show the proper operation for current address reads.

Selective (Random) Read

There is a simple technique that allows a user to select a random address location as the starting point for a read operation. This involves using the first three bytes of a write operation to set the internal address followed by subsequent read operations.

To perform a selective read, the bus master sends out the slave address with the LSB set to 0. This specifies a write operation. According to the write protocol, the bus master then sends the address bytes that are loaded into the internal address latch. After the FM32L27x acknowledges the address, the bus master issues a Start condition. This simultaneously aborts the write operation and allows the read command to be issued with the slave address LSB set to a 1. The operation is now a read from the current address. Read operations are illustrated below.

Companion Write Operation

All Companion writes operate in a similar manner to memory writes. The distinction is that a different device ID is used and only one byte address is needed instead of two. Figure 16 illustrates a single byte write to this device.

Companion Read Operation

As with writes, a read operation begins with the Slave Address. To perform a register read, the bus

master supplies a Slave Address with the LSB set to 1. This indicates that a read operation is requested. After receiving the complete Slave Address, the FM32L27x will begin shifting data out from the current register address on the next clock. Autoincrement operates for the special function registers as with the memory address. A current address read for the registers look exactly like the memory except that the device ID is different.

The FM32L27x contains two separate address registers, one for the memory address and the other for the register address. This allows the contents of one address register to be modified without affecting the current address of the other register. For example, this would allow an interrupted read to the memory while still providing fast access to a companion register. A subsequent memory read will then continue from the memory address where it previously left off, without requiring the load of a new memory address. However, a write sequence always requires an address to be supplied.

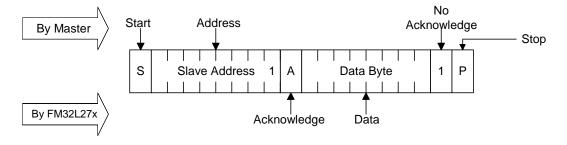


Figure 14. Current Address Memory Read

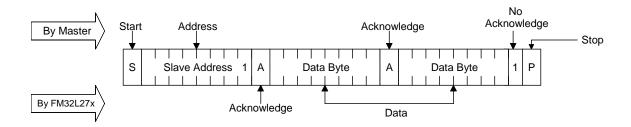


Figure 15. Sequential Memory Read

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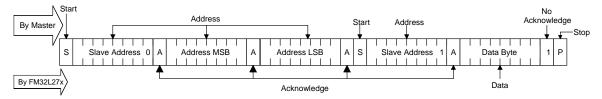


Figure 16. Selective (Random) Memory Read

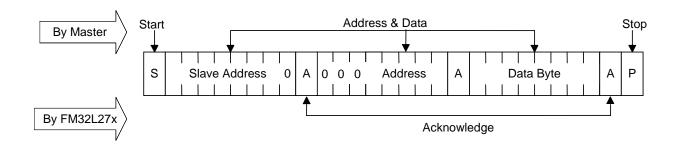


Figure 17. Byte Register Write

Although not required, it is recommended that A5-A7 in the Register Address byte are zeros in order to preserve compatibility with future devices.

Addressing F-RAM Array in the FM32L27x Family

The FM32L27x family includes 256Kb, 64Kb, 16Kb, and 4Kb memory densities. The following 2-byte address field is shown for each density.

Table 4. Two-Byte Memory Address

Part #	1 st Address Byte										2 nd	Addr	ess B	yte		
FM32L278	х	A14	A13	A12	A11	A10	A9	A8	A7	Aб	A5	A4	A3	A2	A1	A0
FM32L276	х	Х	Х	A12	A11	A10	A9	A8	Α7	Аб	A5	A4	A3	A2	A1	A0
FM32L274	х	Х	Х	Х	Х	A10	A9	A8	Α7	Аб	A5	A4	A3	A2	A1	A0
FM32L272	х	х	х	х	х	х	х	A8	Α7	Аб	A5	A4	A3	A2	A1	A0

Electrical Specifications

Absolute Maximum Ratings

Symbol	Description	Ratings
$ m V_{DD}$	Power Supply Voltage with respect to V _{SS}	-1.0V to +5.0V
V_{IN}	Voltage on any signal pin with respect to V _{SS}	-1.0V to +5.0V * and
		$V_{IN} \le V_{DD} + 1.0V **$
$ m V_{BAK}$	Backup Supply Voltage	-1.0V to +4.5V
T_{STG}	Storage Temperature	-55°C to + 125°C
T_{LEAD}	Lead Temperature (Soldering, 10 seconds)	300° C
V_{ESD}	Electrostatic Discharge Voltage	
	- Human Body Model (JEDEC Std JESD22-A114-B)	3kV
	- Charged Device Model (JEDEC Std JESD22-C101-A)	1kV
	Package Moisture Sensitivity Level	MSL-1

^{*} PFI input voltage must not exceed 4.5V.

DC Operating Conditions ($T_A = -40^{\circ} \text{ C to} + 85^{\circ} \text{ C}, V_{DD} = 2.7 \text{ V to } 3.6 \text{ V unless otherwise specified}$)

Symbol	Parameter	Min	Тур	Max	Units	Notes
V_{DD}	Main Power Supply	2.7		3.6	V	7
I_{DD}	V _{DD} Supply Current					1
	@ SCL = 100 kHz			500	μΑ	
	@ SCL = 400 kHz			900	μΑ	
	@ SCL = 1 MHz			1500	μΑ	
I_{SB}	Standby Current			120	μΑ	2
$V_{\rm BAK}$	Backup Supply Voltage	2.0	3.0	3.75	V	9
I _{BAK}	Backup Supply Current			1	μA	4
I_{BAKTC}	Trickle Charge Current with V _{BAK} =0V				,	10
	Fast Charge Off (FC = 0)	50	-	120	μA	
	Fast Charge On (FC = 1)	200	-	2500	μA	
V_{TP1}	V_{DD} Trip Point Voltage, VTP = 0	2.55	2.6	2.70	V	5
V_{TP2}	V_{DD} Trip Point Voltage, VTP = 1	2.85	2.9	3.00	V	5
V_{RST}	V_{DD} for valid /RST @ I_{OL} = 80 μ A at V_{OL}					6
	$V_{BAK} > V_{BAK}$ min	0			V	
	$V_{BAK} < V_{BAK}$ min	1.6			V	
I_{LI}	Input Leakage Current			±1	μΑ	3
I_{LO}	Output Leakage Current			±1	μΑ	3
$V_{\rm IL}$	Input Low Voltage					
	All inputs except those listed below	-0.3		$0.3~\mathrm{V_{DD}}$	V	8
	CNT1-2 battery backed ($V_{DD} < 2.5V$)	-0.3		0.5	V	
	$CNT1-2 (V_{DD} > 2.5V)$	-0.3		0.8	V	
$V_{ m IH}$	Input High Voltage					
	All inputs except those listed below	$0.7~\mathrm{V_{DD}}$		$V_{\rm DD} + 0.3$	V	
	PFI (comparator input)	-		3.75	V	
Ì	CNT1-2 battery backed ($V_{DD} < 2.5V$)	$V_{BAK} - 0.5$		$V_{BAK} + 0.3$	V	
	CNT1-2 V _{DD} > 2.5V	$0.7~\mathrm{V_{DD}}$		$V_{\rm DD} + 0.3$	V	
V_{OL}	Output Low Voltage ($I_{OL} = 3 \text{ mA}$)	-		0.4	V	
V_{OH}	Output High Voltage ($I_{OH} = -2 \text{ mA}$)	2.4		-	V	
R_{RST}	Pull-up Resistance for /RST Inactive	50		400	ΚΩ	

Continued »

^{**} The ${}^{\circ}V_{DD}+1.0V$ " restriction does not apply to the SCL and SDA inputs which do not employ a diode to V_{DD} . Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only, and the functional operation of the device at these or any other conditions above those listed in the operational section of this specification is not implied. Exposure to absolute maximum ratings conditions for extended periods may affect device reliability.

DC Operating Conditions, continued ($T_A = -40^{\circ} \text{ C to} + 85^{\circ} \text{ C}$, $V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$ unless otherwise specified)

Symbol	Parameter	Min	Тур	Max	Units	Notes
R_{IN}	Input Resistance (pulldown)					
	A1-A0 for $V_{IN} = V_{IL}$ max	20			ΚΩ	
	A1-A0 for $V_{IN} = V_{IH}$ min	1			$M\Omega$	
V_{PFI}	Power Fail Input Reference Voltage	1.175	1.20	1.225	V	
V_{HYS}	Power Fail Input (PFI) Hysteresis (Rising)		-	100	mV	

Notes

- SCL toggling between V_{DD} -0.3V and V_{SS} , other inputs V_{SS} or V_{DD} -0.3V.
- 2. All inputs at V_{SS} or V_{DD} static. Stop command issued.
- $V_{\rm IN}$ or $V_{\rm OUT} = V_{\rm SS}$ to $V_{\rm DD}$, static. Stop command issued: $V_{\rm IN}$ or $V_{\rm OUT} = V_{\rm SS}$ to $V_{\rm DD}$. Does not apply to A0, A1, or /RST pins. $V_{\rm BAK} = 3.0 {\rm V}$, $V_{\rm DD} < 2.4 {\rm V}$, oscillator running, CNT1-2 at $V_{\rm BAK}$. /RST is asserted low when $V_{\rm DD} < V_{\rm TP}$. 3.
- 4.
- 5.
- The minimum V_{DD} to guarantee the level of /RST remains a valid V_{OL} level.
- Full complete operation. Supervisory circuits operate to lower voltages as specified.
- Includes /RST input detection of external reset condition to trigger driving of /RST signal by FM32L27x.
- The VBAK trickle charger automatically regulates the maximum voltage on this pin for capacitor backup applications.
- 10. V_{BAK} will source current when trickle charge is enabled (VBC bit=1), $V_{DD} > V_{BAK}$, and $V_{BAK} < V_{BAK}$ max.

AC Parameters ($T_A = -40^{\circ}$ C to +85° C, $V_{DD} = 2.7$ V to 3.6V, $C_I = 100$ pF unless otherwise specified)

Symbol	Parameter	Min	Max	Min	Max	Min	Max	Units	Notes
f_{SCL}	SCL Clock Frequency		100	0	400	0	1000	kHz	
t_{LOW}	Clock Low Period	4.7		1.3		0.6		μs	
t _{HIGH}	Clock High Period	4.0		0.6		0.4		μs	
t_{AA}	SCL Low to SDA Data Out Valid		3		0.9		0.55	μs	
t _{BUF}	Bus Free Before New Transmission	4.7		1.3		0.5		μs	
t _{HD:STA}	Start Condition Hold Time	4.0		0.6		0.25		μs	
t _{SU:STA}	Start Condition Setup for Repeated	4.7		0.6		0.25		μs	
	Start							•	
t _{HD:DAT}	Data In Hold Time	0		0		0		ns	
t _{SU:DAT}	Data In Setup Time	250		100		100		ns	
t_R	Input Rise Time		1000		300		300	ns	1
$t_{\rm F}$	Input Fall Time		300		300		100	ns	1
t _{SU:STO}	Stop Condition Setup Time	4.0		0.6		0.25		μs	
t_{DH}	Data Output Hold (from SCL @ VIL)	0		0		0		ns	
t_{SP}	Noise Suppression Time Constant		50		50		50	ns	
	on SCL, SDA								

All SCL specifications as well as start and stop conditions apply to both read and write operations.

Capacitance $(T_A = 25^{\circ} \text{ C, f}=1.0 \text{ MHz, V}_{DD} = 3.0 \text{ V})$

Symbol	Parameter	Тур	Max	Units	Notes
C_{IO}	Input/Output Capacitance	-	8	рF	1

Notes

This parameter is characterized but not tested.

Data Retention ($V_{DD} = 2.7V \text{ to } 3.6V$)

Symbol	Parameter	Min	Units	Notes
T_{DR}	Data Retention			
	@ +75°C	45	Years	
	@+80°C	20	Years	
	@+85°C	10	Years	

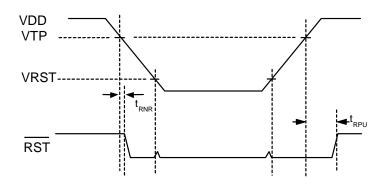
Supervisor Timing ($T_A = -40^{\circ} \text{ C to} + 85^{\circ} \text{ C}, V_{DD} = 2.7 \text{V to } 3.6 \text{V}$)

Symbol	Parameter	Min	Max	Units	Notes
$t_{ m RPU}$	/RST Active (low) after V _{DD} >V _{TP}	100	200	ms	
t_{RNR}	$V_{DD} < V_{TP}$ noise immunity	10	25	μs	1
t_{VR}	V _{DD} Rise Time	50	-	μs/V	1,2
t_{VF}	V _{DD} Fall Time	100	-	μs/V	1,2
t_{WDP}	Pulse Width of /RST for Watchdog Reset	100	200	ms	
$t_{ m WDOG}$	Timeout of Watchdog	t_{DOG}	2*t _{DOG}	ms	3
f_{CNT}	Frequency of Event Counters	0	10	MHz	

Notes

- This parameter is characterized but not tested.
- Slope measured at any point on V_{DD} waveform. t_{DOG} is the programmed time in register 0Ah, $V_{DD} > V_{TP}$ and t_{RPU} satisfied.

/RST Timing



AC Test Conditions

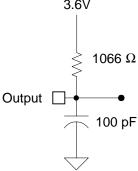
Input Pulse Levels $0.1 V_{DD}$ to $0.9 V_{DD}$

Input rise and fall times 10 ns
Input and output timing levels 0.5 V_{DD}

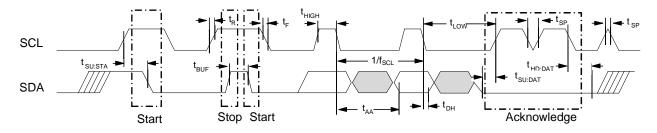
Diagram Notes

All start and stop timing parameters apply to both read and write cycles. Clock specifications are identical for read and write cycles. Write timing parameters apply to slave address, word address, and write data bits. Functional relationships are illustrated in the relevant data sheet sections. These diagrams illustrate the timing parameters only.

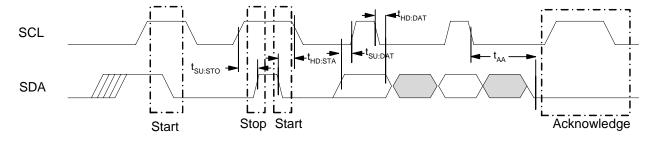
Equivalent AC Load Circuit 3.6V



Read Bus Timing

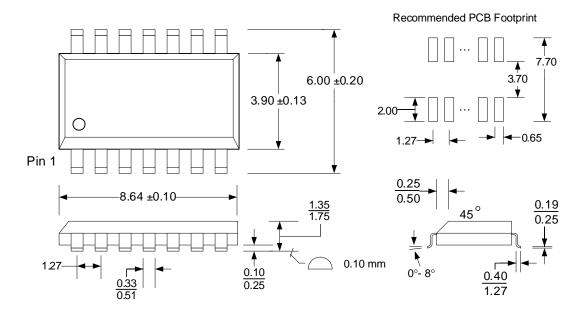


Write Bus Timing

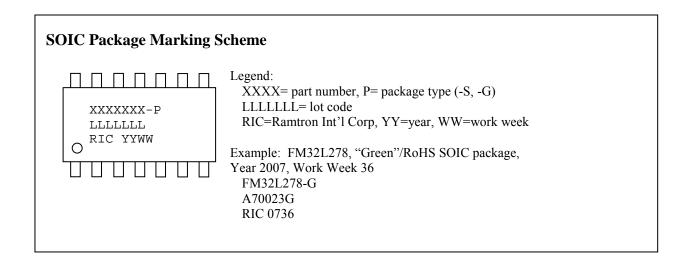


Mechanical Drawing

14-pin SOIC (JEDEC Standard MS-012, Variation AB)



Refer to JEDEC MS-012 for complete dimensions and notes. All dimensions in millimeters.



Revision History

Revision	Date	Summary
2.0	12/14/07	Initial release.
3.0	2/9/2009	Changed status to Production. Added tape and reel ordering information.
		Expanded data retention ratings. Added UL Recognition of trickle charger.

Rev. 3.0 Feb. 2009